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FDS4935BZ

Dual 30 Volt P-Channel PowerTrench® MOSFET General Description

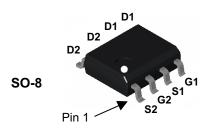
This P-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers, and battery chargers.

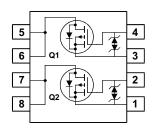
These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable $R_{\text{DS(ON)}}$ specifications.

The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

Features

- -6.9 A, -30 V. $R_{DS(ON)}$ = 22 m Ω @ V_{GS} = -10 V $R_{DS(ON)}$ = 35 m Ω @ V_{GS} = -4.5 V
- $\bullet~$ Extended V_{GSS} range (–25V) for battery applications
- ESD protection diode (note 3)
- High performance trench technology for extremely low $R_{\mbox{\scriptsize DS(ON)}}$
- · High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DS\}	Drain-Source Voltage		-30	V
V _{GS}	Gate-Source Voltage		<u>+</u> 25	V
I _D	Drain Current - Continuous	(Note 1a)	-6.9	Α
	– Pulsed		-50	
P _D	Power Dissipation for Single Operation	(Note 1a)	1.6	W
		(Note 1b)	1.0	
		(Note 1c)	0.9	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

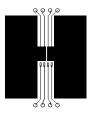
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	40	°C/W

Package Marking and Ordering Information

- u.c.mage		9	j				
	Device Marking	Device	Reel Size	Tape width	Quantity		
-	FDS4935BZ	FDS4935BZ	13"	12mm	2500 units		

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics			l		l
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \qquad I_{D} = -250 \mu\text{A}$	-30			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A,Referenced to 25°C		24		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -24 V, V _{GS} = 0 V			-1	μА
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			<u>+</u> 10	μΑ
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1	-1.9	-3	V
$\Delta V_{GS(th)} \over \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	I_D = -250 μ A,Referenced to 25°C		- 5		mV/°C
r _{DS(on)}	Static Drain–Source On–Resistance	$V_{GS} = -10 \text{ V}, I_D = -6.9 \text{ A}$ $V_{GS} = -4.5 \text{ V}, I_D = -5.3 \text{ A}$ $V_{GS} = -10 \text{ V}, I_D = -6.9 \text{ A}, T_J = 125 ^{\circ}\text{ C}$		18 27.5 26	22 35 34	mΩ
g _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, I_{D} = -6.9 \text{ A}$		22		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V},$		1360		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		240		pF
C _{rss}	Reverse Transfer Capacitance	7		200		pF
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -15 \text{ V}, I_D = -1 \text{ A},$		12	22	ns
t _r	Turn-On Rise Time	$V_{GS} = -10 \text{ V}, R_{GEN} = 6 \Omega$		13	23	ns
t _{d(off)}	Turn-Off Delay Time	7		68	108	ns
t _f	Turn-Off Fall Time	7		38	61	ns
Q _{g(TOT)}	Total Gate Charge, V _{GS} = 10V	$V_{DS} = -15 \text{ V}, I_{D} = -6.9 \text{ A},$		29	40	nC
Q _{g(TOT)}	Total Gate Charge, V _{GS} = 5V	V _{GS} = -10 V		16	23	nC
Q _{gs}	Gate-Source Charge	7		4		nC
Q _{gd}	Gate-Drain Charge	7		7		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings			•	•
Is	Maximum Continuous Drain–Source				-2.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	V _{GS} = 0 V, I _S = -2.1 A (Note 2)	_	-0.8	-1.2	V
t _{RR}	Reverse Recovery Time	I _F = -8.8 A,		24		ns
Q _{RR}	Reverse Recovery Charge	$d_{iF}/d_t = 100 \text{ A/}\mu\text{s} \qquad \text{(Note 2)}$		9		nC

1. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $\rm R_{\theta JC}$ is guaranteed by design while $\rm R_{\theta CA}$ is determined by the user's board design.



a) 78°C/W steady state when mounted on a 1in² pad of 2 oz copper



b) 125°C/W when mounted on a .04 in² pad of 2 oz copper



c) 135°C/W when mounted on a minimum pad.

- Scale 1:1 on letter size paper
- 2. Pulse Test: Pulse Width < $300\mu s,$ Duty Cycle < 2.0%
- 3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics

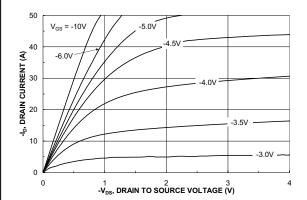


Figure 1. On-Region Characteristics.

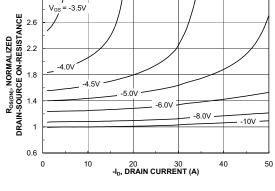


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

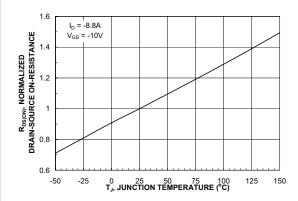


Figure 3. On-Resistance Variation with Temperature.

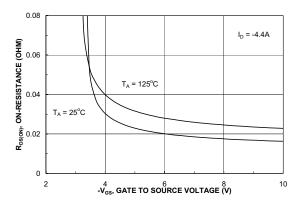


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

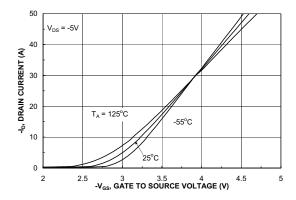


Figure 5. Transfer Characteristics.

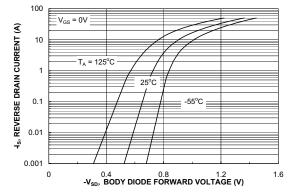
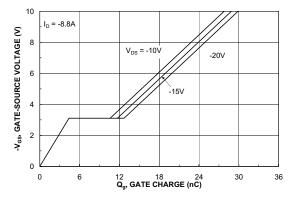


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics



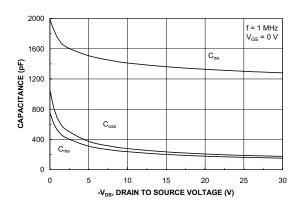
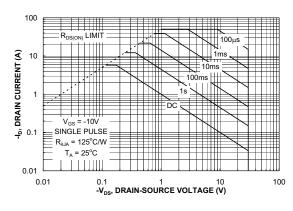


Figure 7. Gate Charge Characteristics.





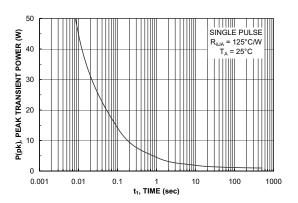


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

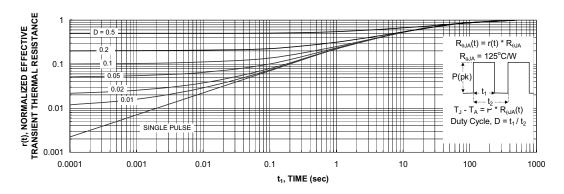


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1c. Transient thermal response will change depending on the circuit board design.

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